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- $^{\bullet}$ Many masking steps needed, plus CMP required \rightarrow cost can grow if you're not careful
- Processes using trenches sacrifice lithographic resolution in microstructures
- MEMS must withstand transistor processing temperatures
 Precludes the use of structural materials with low temperature req'mts: metals, polymers, etc.
- Exotic MEMS (e.g., ZnO) that can contaminate transistors during their processing are not permissible
 thus, not truly modular
- Foundry acceptance not guaranteed and might be rare

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Foundry Acceptance of MEMS-First?

- Is a CMP'ed silicon surface sufficiently pure for fabrication of aggressively scaled transistors? How about if an oxide is grown over the CMP'ed surface and removed via a wet etch to yield a "pristine" surface?
- Is epi silicon grown as part of a sealing process sufficiently pure for fabrication of aggressively scaled transistors?
- CMOS is many times more difficult to run than MEMS
 - \$ Feature sizes on the nm scale for billions of devices
 - Contamination a big issue: many foundries may not accept pre-processed wafers for contamination reasons
 - Many foundries will not accept any pre-processed wafers, MEMS or not → just can't guarantee working transistor circuits with unknowns in starting silicon

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